30V Nch+Nch Middle Power MOSFET

| V _{DSS} | 30V |
|----------------------------|-------|
| R _{DS(on)} (Max.) | 42mΩ |
| I _D | ±5.5A |
| P _D | 2W |

Features

- 1) Low on resistance.
- 2) Small Surface Mount Package .
- 3) Pb-free lead plating; RoHS compliant.
- 4) Halogen Free.

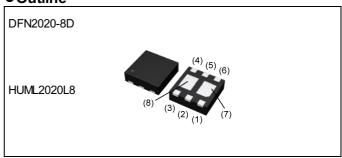
Application

Load Switch

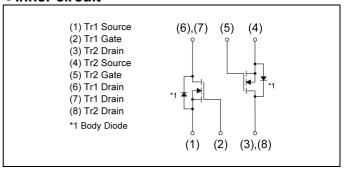
Battery Switch for mobile

DC/DC Converter

Outline



•Inner circuit



Packaging specifications

| <u> </u> | Jing specifications | |
|----------|---------------------------|------------------|
| | Packing | Embossed Tape |
| | Reel size (mm) | 180 |
| Туре | Tape width (mm) | 8 |
| | Basic ordering unit (pcs) | 3000 |
| | Taping code | TCR |
| | Marking | K03 |

● Absolute maximum ratings (T_a = 25°C ,unless otherwise specified) < Tr1 and Tr2>

| Parameter | Symbol | Value | Unit |
|--|--------------------|-------------|------|
| Drain - Source voltage | V _{DSS} | 30 | V |
| Continuous drain current | I _D | ±5.5 | А |
| Pulsed drain current | I _{DP} *1 | ±12 | А |
| Gate - Source voltage | V _{GSS} | ±12 | V |
| Avalanche current, single pulse | I _{AS} *2 | 5.5 | Α |
| Avalanche energy, single pulse | E _{AS} *2 | 2.4 | mJ |
| Power dissipation | P _D *3 | 2 | W |
| Junction temperature | T _j | 150 | °C |
| Operating junction and storage temperature range | T _{stg} | -55 to +150 | °C |

●Thermal resistance

| Parameter | Cymhol | Values | | | Lloit |
|--|----------------------|--------|------|------|-------|
| Parameter | Symbol | Min. | Тур. | Max. | Unit |
| Thermal resistance, junction - ambient | R _{thJA} *3 | 1 | - | 62.5 | °C/W |

● Electrical characteristics (T_a = 25°C) < Tr1 and Tr2>

| Damanatan | 0 | 0 - 1141 - 11 - | Values | | | 1.1 | |
|--|---|--|-----------|------|------|--------|--|
| Parameter | Symbol | Conditions | Min. Typ. | | Max. | - Unit | |
| Drain - Source breakdown voltage | V _{(BR)DSS} | V _{GS} = 0V, I _D = 1mA | | - | - | V | |
| Breakdown voltage temperature coefficient | $\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$ | I _D = 1mA referenced to 25°C | | 18 | - | mV/°C | |
| Zero gate voltage drain current | I _{DSS} | V _{DS} = 30V, V _{GS} = 0V | | - | 1 | μA | |
| Gate - Source leakage current | I _{GSS} | V _{DS} = 0V, V _{GS} = ±12V | | - | ±100 | nA | |
| Gate threshold voltage | V _{GS(th)} | $V_{DS} = V_{GS}$, $I_D = 1mA$ | 0.5 | - | 1.5 | V | |
| Gate threshold voltage temperature coefficient | $\frac{\DeltaV_{\text{GS(th)}}}{\DeltaT_j}$ | | | -1.8 | - | mV/°C | |
| Static drain - source | D *4 | V _{GS} = 4.5V, I _D = 5.0A | - | 30 | 42 | m0 | |
| on - state resistance | R _{DS(on)} *4 | V _{GS} = 2.5V, I _D = 2.75A | - | 45 | 63 | mΩ | |
| Gate resistance | R_G | f=1MHz, open drain | ı | 2.2 | - | Ω | |
| Forward Transfer Admittance | Y _{fs} *4 | V _{DS} = 5.0V, I _D = 5.0A | 2.3 | - | - | S | |

^{*1} Pw \leq 10µs, Duty cycle \leq 1%

^{*2} L \simeq 0.1mH, V_{DD} = 15V, R_G = 25 Ω , STARTING T $_{j}$ = 25 $^{\circ}$ C Fig.3-1,3-2

^{*3} Mounted on a Cu boad (40×40×0.8mm)

^{*4} Pulsed

● Electrical characteristics (T_a = 25°C) < Tr1 and Tr2>

| Parameter | Cumbal | Conditions | Values | | | Unit | |
|------------------------------|------------------------|--|--------|------|------|-------|--|
| Parameter | Symbol Conditions — | | Min. | Тур. | Max. | Orlit | |
| Input capacitance | C _{iss} | V _{GS} = 0V | - | 450 | - | | |
| Output capacitance | C _{oss} | V _{DS} = 15V | - | 50 | - | pF | |
| Reverse transfer capacitance | C_{rss} | f = 1MHz | - | 35 | - | | |
| Turn - on delay time | t _{d(on)} *4 | V _{DD} ≈ 15V,V _{GS} = 4.5V | - | 7.2 | - | | |
| Rise time | t _r *4 | I _D = 2.75A | - | 5.8 | - | | |
| Turn - off delay time | t _{d(off)} *4 | $R_L = 6\Omega$ | - | 13 | - | ns | |
| Fall time | t _f *4 | $R_G = 10\Omega$ | - | 5.1 | - | | |

● Gate charge characteristics (T_a = 25°C) < Tr1 and Tr2>

| Parameter | Symbol | Conditions | Values | | | Unit |
|----------------------|--------------------|---|--------|------|------|-------|
| raianietei | Symbol | Conditions | Min. | Тур. | Max. | Offic |
| Total gate charge | Q_g^{*4} | | - | 4.0 | - | |
| Gate - Source charge | Q _{gs} *4 | $V_{DD} \approx 15V, I_{D} = 5.5A$ $V_{GS} = 4.5V$ | - | 1.0 | - | nC |
| Gate - Drain charge | Q _{gd} *4 | 1.63 | - | 1.0 | - | |

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

<Tr1 and Tr2>

| Parameter | Symbol Conditions - | | Values | | | Unit |
|----------------------------|---------------------|-----------------------------|--------|------|------|-------|
| raianetei | | | Min. | Тур. | Max. | Offic |
| Continuous forward current | I _S | T _a = 25°C | - | - | 1.6 | А |
| Pulse forward current | I _{SP} *1 | | - | - | 12 | |
| Forward voltage | V_{SD}^{*4} | $V_{GS} = 0V, I_{S} = 1.6A$ | - | ı | 1.2 | V |

Fig.1 Power Dissipation Derating Curve

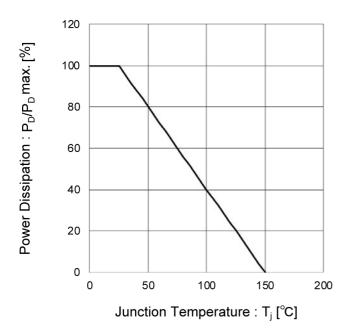
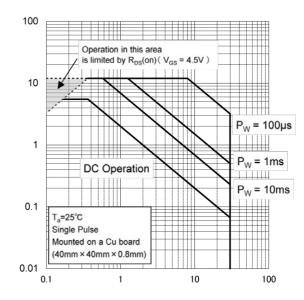


Fig.2 Maximum Safe Operating Area



Drain Current : I_D [A]

Drain - Source Voltage: V_{DS}[V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

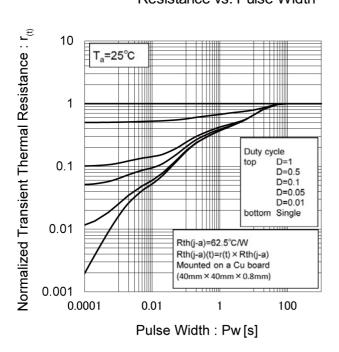
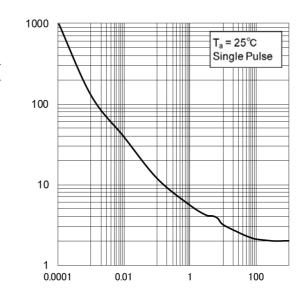


Fig.4 Single Pulse Maximum Power dissipation



Pulse Width: Pw[s]

Peak Transient Power: P(W)

Fig.5 Typical Output Characteristics(I)

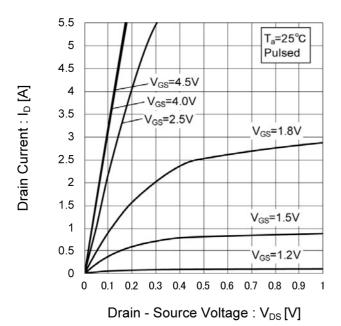
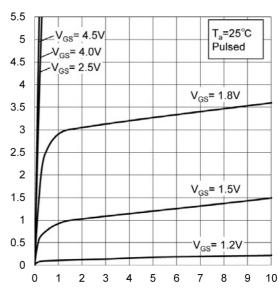


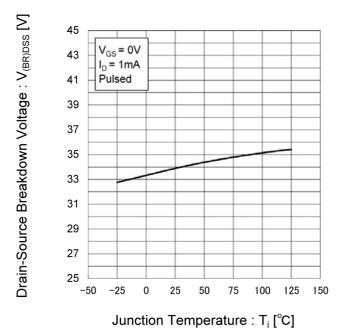
Fig.6 Typical Output Characteristics(II)



Drain Current : I_D [A]

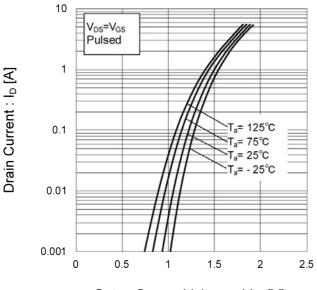
Drain - Source Voltage : V_{DS} [V]

Fig.7 Breakdown Voltage vs. Junction Temperature



ROHM

Fig.8 Typical Transfer Characteristics



Gate - Source Voltage : V_{GS} [V]

Fig.9 Gate Threshold Voltage vs. Junction Temperature

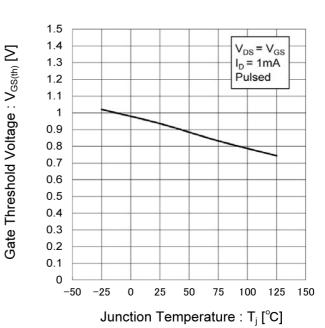


Fig.10 Forward Transfer Admittance vs. Drain Current

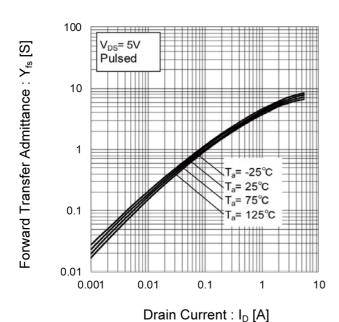


Fig.11 Drain Current Derating Curve

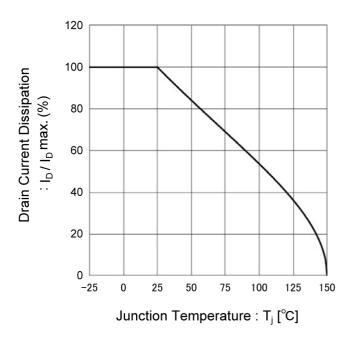


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

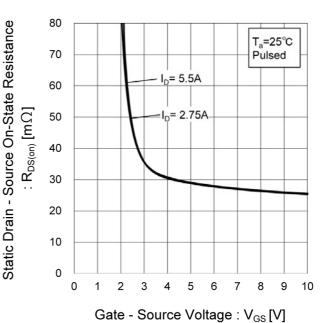


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

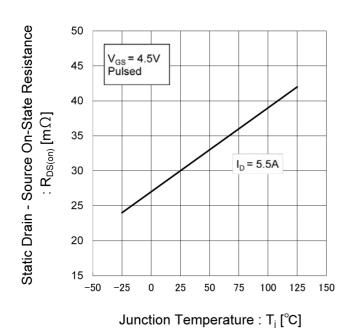


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current(I)

Static Drain Current : I_D [A]

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)

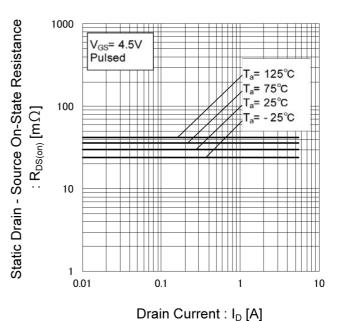


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III)

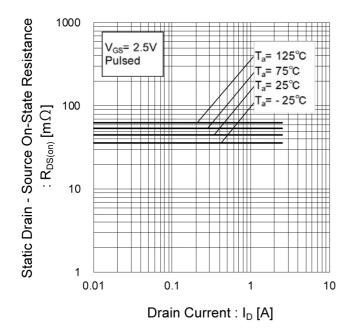


Fig.17 Typical Capacitance vs. Drain - Source Voltage

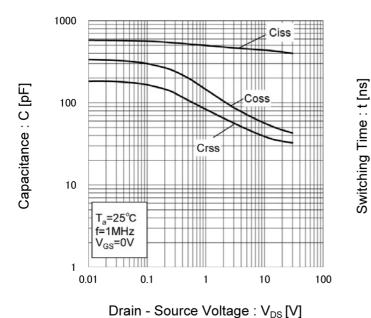
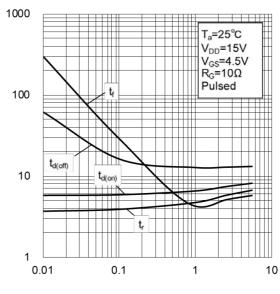
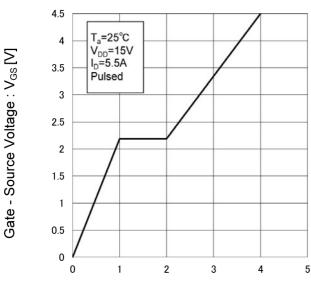


Fig.18 Switching Characteristics



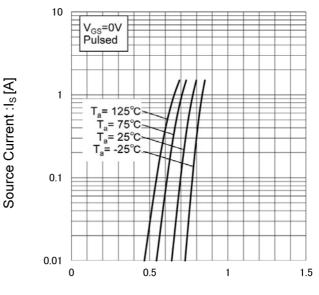
Drain Current : I_D [A]

Fig.19 Dynamic Input Characteristics



Total Gate Charge : Q_q [nC]

Fig.20 Source Current vs. Source Drain Voltage



Source-Drain Voltage: V_{SD}[V]

• Measurement circuits < It is the same for the Tr1 and Tr2>

Fig.1-1 Switching Time Measurement Circuit

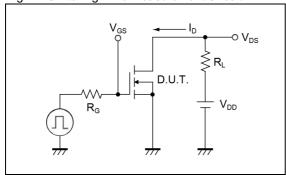


Fig.2-1 Gate Charge Measurement Circuit

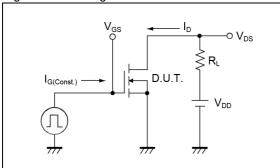


Fig.3-1 Avalanche Measurement Circuit

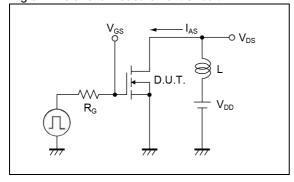


Fig.1-2 Switching Waveforms

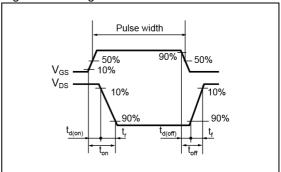


Fig.2-2 Gate Charge Waveform

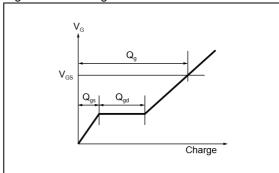
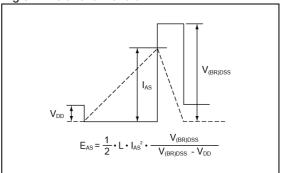


Fig.3-2 Avalanche Waveform

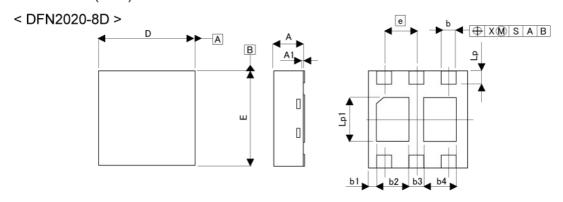


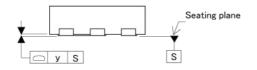
Notice

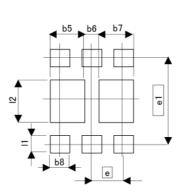
This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

Dimensions

HUML2020L8 (Dual)







Pattern of terminal position areas [Not a pattern of soldering pads]

| | MILIMETERS INCHES | | | | | |
|-------|-------------------|-------|-------|-------|--|--|
| DIM | MILIME | TERS | INC | HES | | |
| Diivi | MIN | MAX | MIN | MAX | | |
| Α | 0.55 | 0.65 | 0.022 | 0.026 | | |
| A1 | 0.00 | 0.05 | 0.000 | 0.002 | | |
| b | 0.25 | 0.35 | 0.010 | 0.014 | | |
| b1 | 0. | 25 | 0.0 |)10 | | |
| b2 | 0.60 | 0.70 | 0.024 | 0.028 | | |
| b3 | 0 | .3 | 0.012 | | | |
| b4 | 0.60 | 0.70 | 0.024 | 0.028 | | |
| D | 1.90 | 2.10 | 0.075 | 0.083 | | |
| Е | 1.90 | 2.10 | 0.075 | 0.083 | | |
| е | 0. | 65 | 0.0 |)26 | | |
| Lp | 0.225 | 0.325 | 0.009 | 0.013 | | |
| Lp1 | 0.80 | 1.00 | 0.031 | 0.039 | | |
| х | - | 0.10 | E-1 | 0.004 | | |
| у | - | 0.10 | | 0.004 | | |

| DIM | MILIME | ETERS | INC | HES |
|-------|--------|-------|-------|-------|
| Dilvi | MIN | MAX | MIN | MAX |
| b5 | - | 0.70 | - | 0.028 |
| b6 | 0.20 | 0.30 | 0.008 | 0.012 |
| b7 | - | 0.70 | - | 0.028 |
| b8 | - | 0.45 | - | 0.018 |
| e1 | 1.7 | 725 | 0.068 | |
| I1 | - | 0.425 | 9.5 | 0.017 |
| 12 | - | 1.00 | 1- | 0.039 |

Dimension in mm/inches



Notice

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|---------|-----------|------------|-------------|
| CLASSⅢ | CL ACCIII | CLASS II b | CL A C C TT |
| CLASSIV | CLASSⅢ | CLASSⅢ | CLASSIII |

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 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
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- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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